

GMBT2411

NPN SILICON PLANAR MEDIUM POWER TRANSISTOR

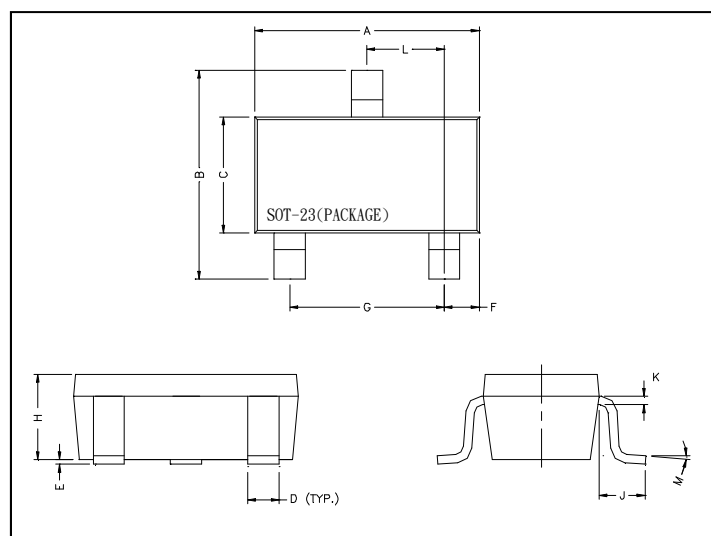
Description

The GMBT2411 is designed for medium power amplifier applications.

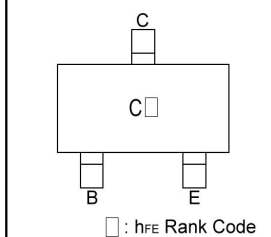
Features

- $I_{CMax}=500mA$
- Low $V_{CE(sat)}$. Optimal for low voltage operation.
- Complementary to GMBT1036

Package Dimensions



Marking :



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	2.70	3.10	G	1.90	REF.
B	2.40	2.80	H	1.00	1.30
C	1.40	1.60	K	0.10	0.20
D	0.35	0.50	J	0.40	-
E	0	0.10	L	0.85	1.15
F	0.45	0.55	M	0°	10°

Absolute Maximum Ratings at $T_a = 25^\circ C$

Parameter	Symbol	Ratings	Unit
Junction Temperature	T_j	+150	$^\circ C$
Storage Temperature	T_{stg}	-55~+150	$^\circ C$
Collector to Base Voltage	V_{CB0}	40	V
Collector to Emitter Voltage	V_{CE0}	32	V
Emitter to Base Voltage	V_{EB0}	5	V
Collector Current	I_C	500	mA
Total Power Dissipation	P_D	225	mW

Electrical Characteristics ($T_a = 25^\circ C$, unless otherwise stated)

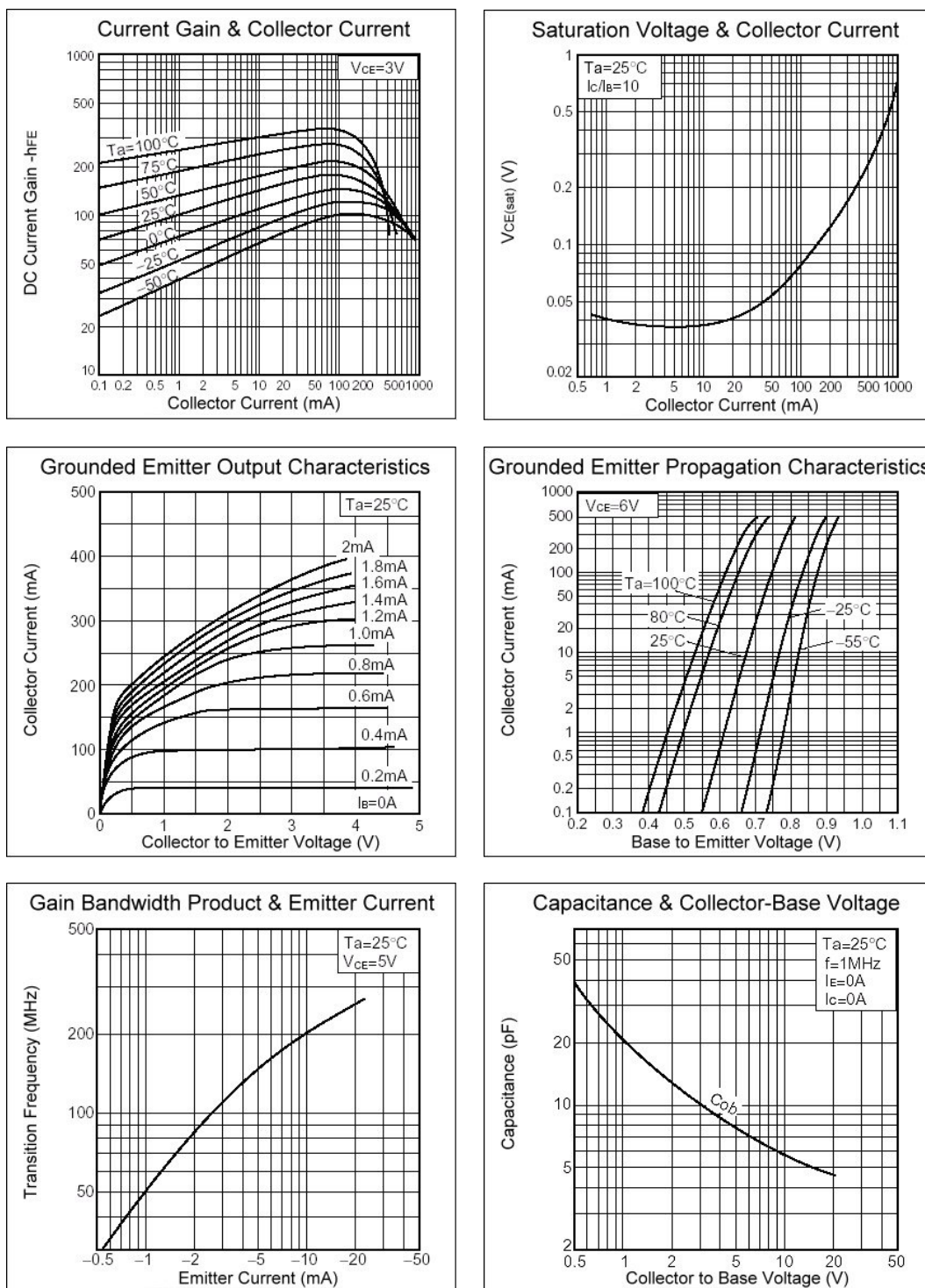
Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV_{CB0}	40	-	-	V	$I_C=100\mu A, I_E=0$
BV_{CE0}	32	-	-	V	$I_C=1mA, I_B=0$
BV_{EB0}	5	-	-	V	$I_E=100\mu A, I_C=0$
I_{CB0}	-	-	1	μA	$V_{CB}=20V, I_E=0$
I_{EB0}	-	-	1	μA	$V_{EB}=4V, I_C=0$
* $V_{CE(sat)}$	-	-	400	mV	$I_C=500mA, I_B=50mA$
* h_{FE}	82	-	390		$V_{CE}=3V, I_C=100mA$
f_T	-	250	-	MHz	$V_{CE}=5V, I_E=-20mA, f=100MHz$
C_{ob}	-	6	-	pF	$V_{CB}=10V, I_E=0, f=1MHz$

*Measured under pulse condition. Pulse width=300 μs , Duty Cycle $\leq 2\%$

Classification Of h_{FE}

Rank	CP	CQ	CR
Range	82 - 180	120 - 270	180 - 390

Characteristics Curve



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